

STPS3030/CT/CG/CR

Low drop power Schottky rectifier

Main product characteristics

I _{F(AV)}	2 x 15 A
V _{RRM}	30 V
T _j (max)	150° C
V _F (max)	0.42 V

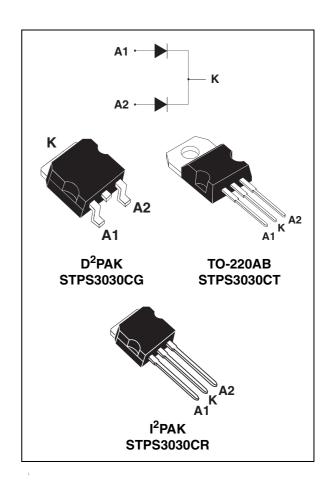
Features and benefits

- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Low forward voltage drop for higher efficiency
- Low thermal resistance
- Avalanche capability specified

Description

Dual Schottky rectifier suited for switch mode power supply and high frequency DC to DC converters.

Packaged in TO-220AB, D²PAK and I²PAK, this device is intended for use in low voltage high frequency inverters, free-wheeling and polarity protection applications.



STPS3030CT/CG/CR **Characteristics**

Characteristics 1

Table 1. Absolute ratings (limiting values, per diode)

Symbol	Parameter	Value	Unit		
V_{RRM}	Repetitive peak reverse voltage	Repetitive peak reverse voltage			V
I _{F(RMS)}	RMS forward current			30	Α
ı	Average femuera ourrent	T _c = 135° C	Per diode	15	Α
'F(AV)	I _{F(AV)} Average forward current	$\delta = 0.5$	Per device	30	A
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal		250	Α
I _{RRM}	Peak repetitive reverse current	t _p = 2 μs square F= 1 kHz		1	Α
I _{RSM}	Non repetitive peak reverse current	t _p = 100 μs s	quare	3	Α
P _{ARM}	Repetitive peak avalanche power $t_p = 1 \mu s$ $T_j = 25^{\circ} C$			4100	W
T _{stg}	Storage temperature range			-65 to + 150	°C
Tj	Maximum operating junction temperature (1)			150	°C
dV/dt	Critical rate of rise of reverse voltage (rated V_R , $T_j = 25^{\circ}$ C)			10000	V/µs

^{1.} $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 2. Thermal resistance

Symbol	Parameter	Value	Unit	
D	Junction to case TO-220AB - D ² PAK - I ² PAK	Per diode	1.2	
R _{th(j-c)}		Total	8.0	°C/W
R _{th(c)}		Coupling	0.4	

Table 3. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
. (1)	I _R ⁽¹⁾ Reverse leakage current	T _j = 25° C	$V_R = V_{RRM}$		0.23	1.0	mA
'R`		T _j = 125° C			125	180	
	V _F ⁽¹⁾ Forward voltage drop	T _j = 25° C	I _F = 15 A		0.44	0.49	
V _E (1)		T _j = 125° C	I _F = 15 A		0.36	0.40	V
VEV Tronward voltage drop	Tronward voltage drop	T _j = 25° C	I _F = 30 A		0.53	0.58	V
		T _j = 125° C	I _F = 30 A		0.49	0.53	

^{1.} Pulse test: tp = 380 μ s, δ < 2%

To evaluate the conduction losses use the following equation: P = 0.26 x $I_{F(AV)}$ + 0.0107 I_{F}^{2} _(RMS)

$$P = 0.26 \text{ x } I_{F(AV)} + 0.0107 I_{F(RMS)}^2$$

STPS3030CT/CG/CR Characteristics

Figure 1. Conduction losses versus average Figure 2. Average forward current versus current current with ambient temperature (δ = 0.5)

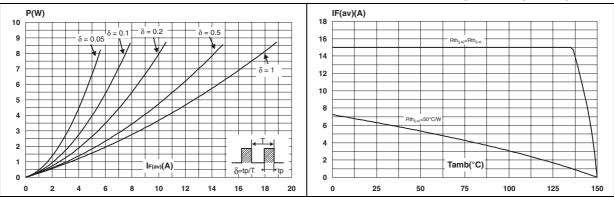


Figure 3. Normalized avalanche power derating versus pulse duration

Figure 4. Normalized avalanche power derating versus junction temperature

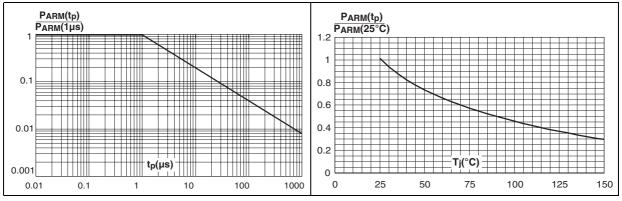
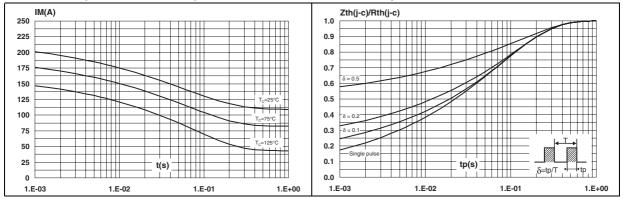


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values)

Figure 6. Relative variation of thermal impedance junction to case versus pulse duration



577

Characteristics STPS3030CT/CG/CR

Figure 7. Reverse leakage current versus reverse voltage applied (typical values)

Figure 8. Junction capacitance versus reverse voltage applied (typical values)

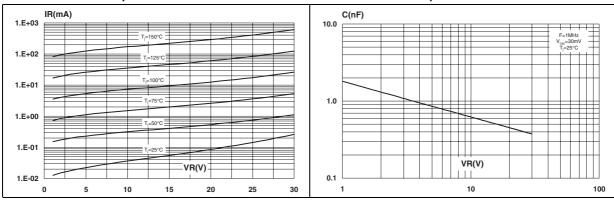
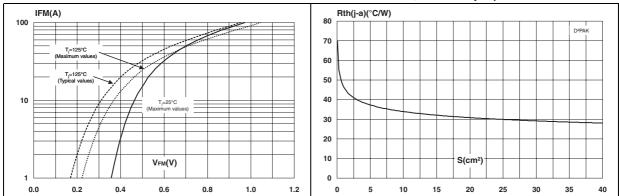


Figure 9. Forward voltage drop versus forward current

Figure 10. Thermal resistance junction to ambient versus copper surface under tab (epoxy printed board FR4, Cu = 35 µm)



4/9

STPS3030CT/CG/CR Package information

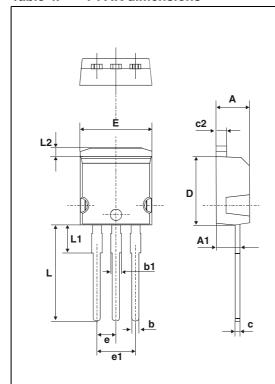
2 Package information

• Epoxy meets UL94,V0

Cooling method: C

Recommended torque value: 0.55 NmMaximum torque value: 0.70 Nm

Table 4. I²PAK dimensions



	Dimensions				
Ref.	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
Α	4.40	4.60	0.173	0.181	
A1	2.40	2.72	0.094	0.107	
b	0.61	0.88	0.024	0.035	
b1	1.14	1.70	0.044	0.067	
С	0.49	0.70	0.019	0.028	
c2	1.23	1.32	0.048	0.052	
D	8.95	9.35	0.352	0.368	
е	2.40	2.70	0.094	0.106	
e1	4.95	5.15	0.195	0.203	
Е	10	10.40	0.394	0.409	
L	13	14	0.512	0.551	
L1	3.50	3.93	0.138	0.155	
L2	1.27	1.40	0.050	0.055	

577

Package information STPS3030CT/CG/CR

Table 5. D²PAK dimensions

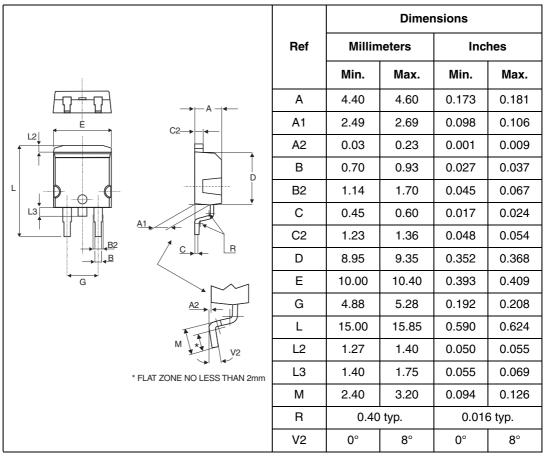
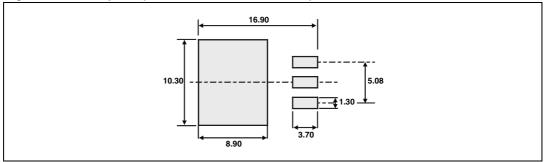


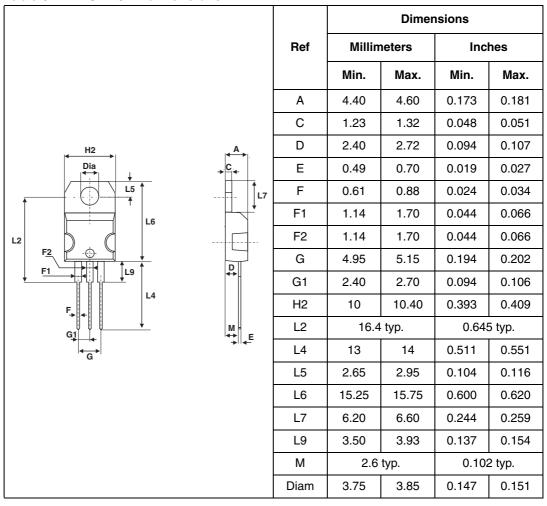
Figure 11. Footprint (dimensions in millimeters)



6/9

STPS3030CT/CG/CR Package information

Table 6. TO-220AB dimensions



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

7/9

3 Ordering information

Ordering type	Marking Package Weight		Weight	Base qty	Delivery mode
STPS3030CT	STPS3030CT	TO-220AB	2.2 g	50	Tube
STPS3030CG	STPS3030CG	D ² PAK	1.48 g	50	Tube
STPS3030CG-TR	STPS3030CG	D ² PAK	1.48 g	1000	Tape and reel
STPS3030CR	STPS3030CR	I ² PAK	1.49 g	50	Tube

4 Revision history

Date	Revision	Changes
Jul-2006	3A	Initial release.
16-Oct-2006	4	Reformatted to current standards. Corrected dimensions for I ² PAK in Table 4

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57

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